

特性

SOP-8 P MOS

Double P-CHANNEL MOSFET in a SOP-8 Plastic Package.

参数

$V_{DS} = -60V$; $I_D = -3.5A$

$R_{DS(on)1} @ -10V \leq 100m\Omega$ (Type.83m Ω)

$R_{DS(on)2} @ -4.5V \leq 130m\Omega$ (Type.100m Ω)

AEC-Q101

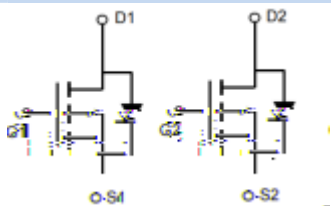
Qualified to AEC-Q101 Standards for High Reliability,

HF Product.

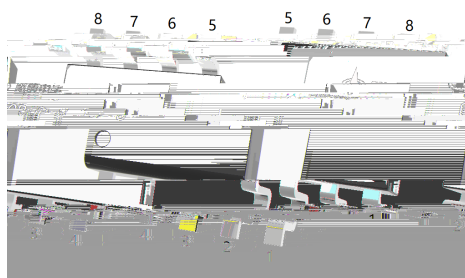
应用

Power Management in Computer, Portable Equipment and Battery Powered Systems, Load Switches, Motor Control, Meet the stringent requirements of automotive applications.

封装与引脚图



封装尺寸



PIN1	S1	PIN 2	G1	PIN 3	S2	PIN 4	G2
PIN 5	D2	PIN 6	D2	PIN 7	D1	PIN 8	D1

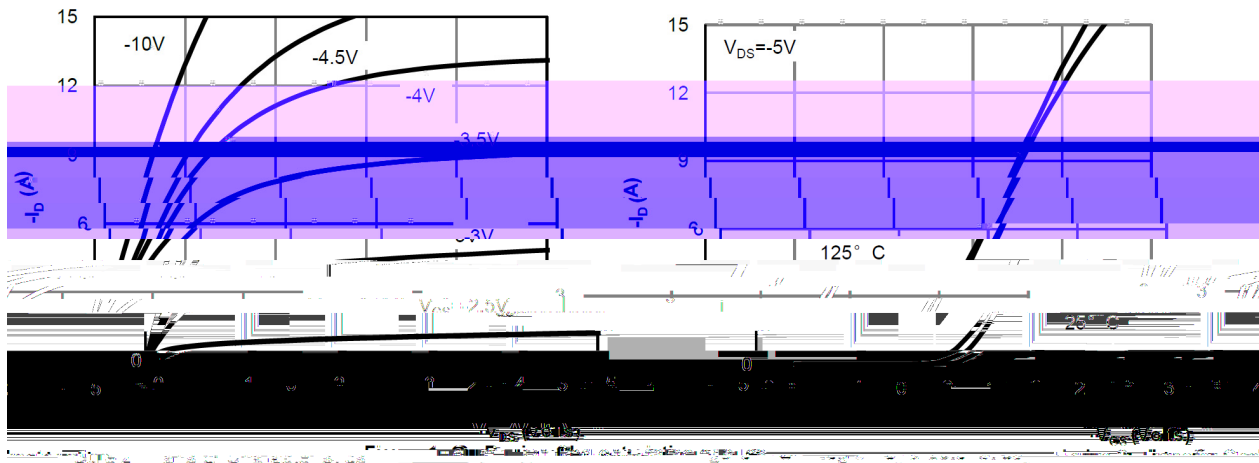
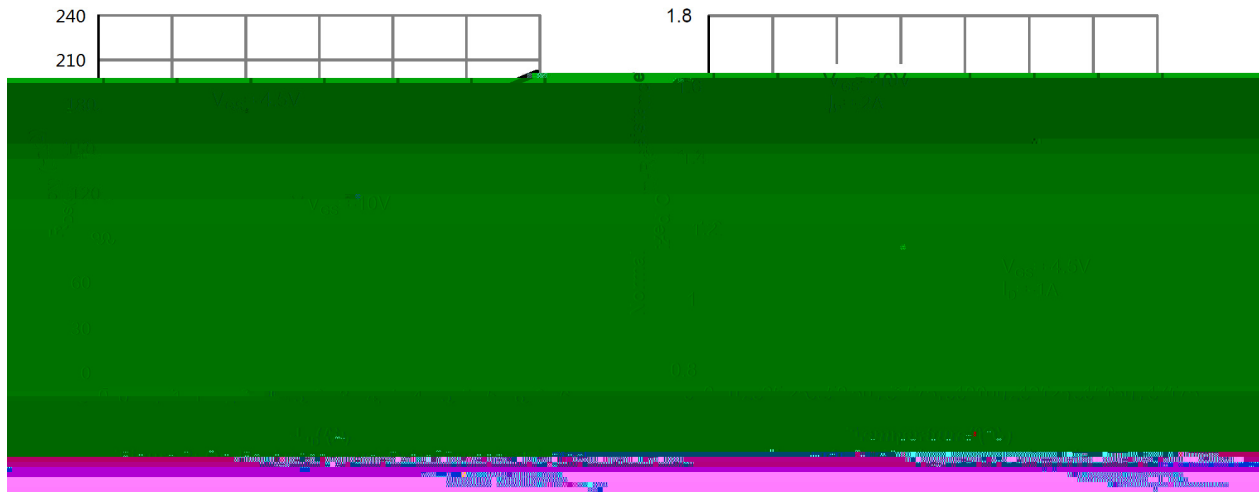
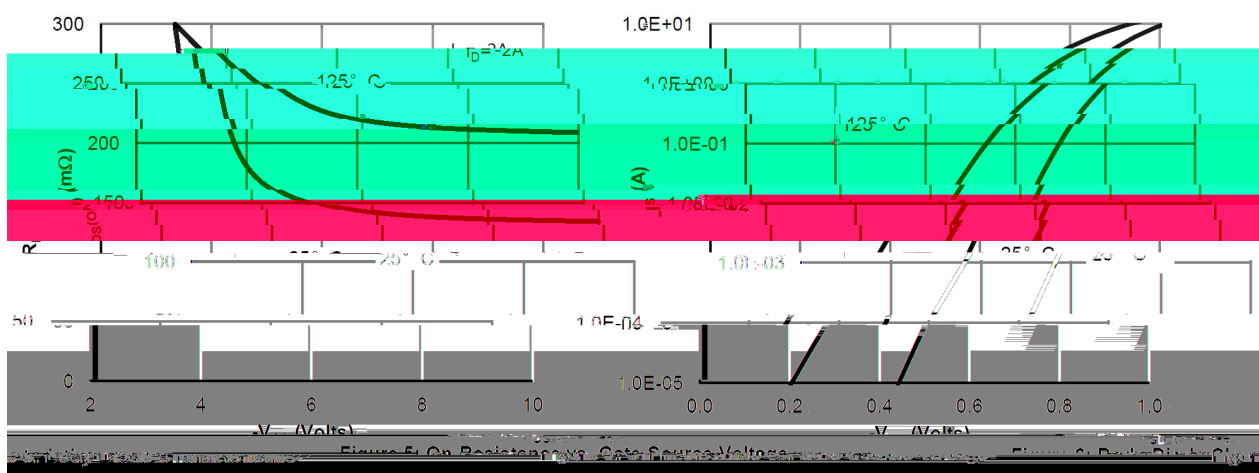
标记

See Marking Instructions.

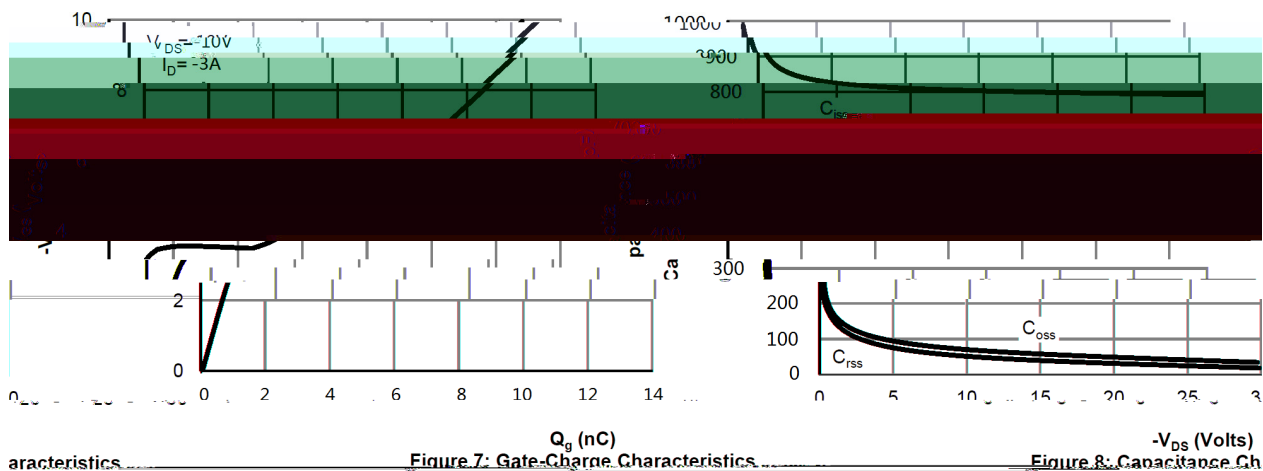
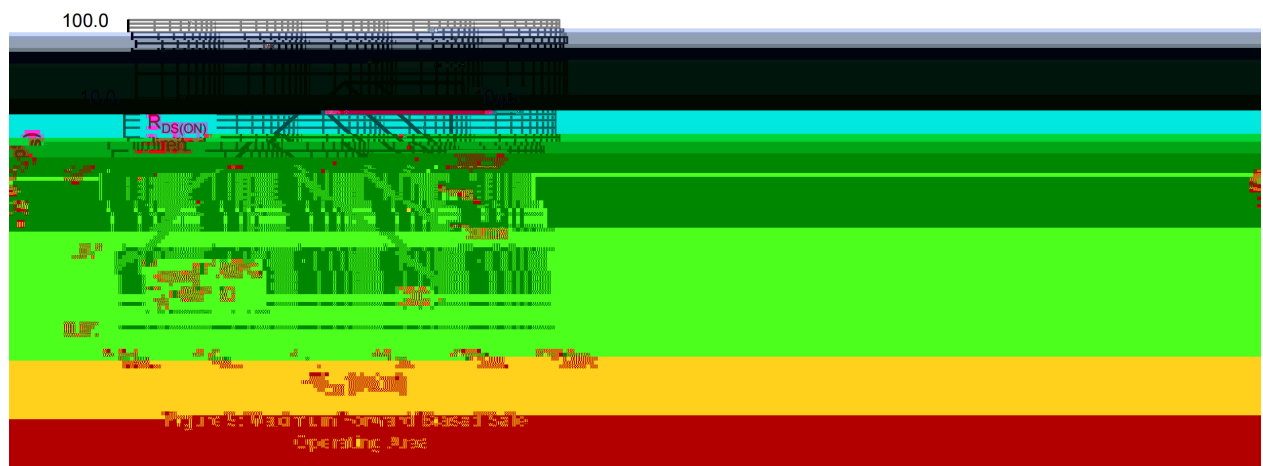
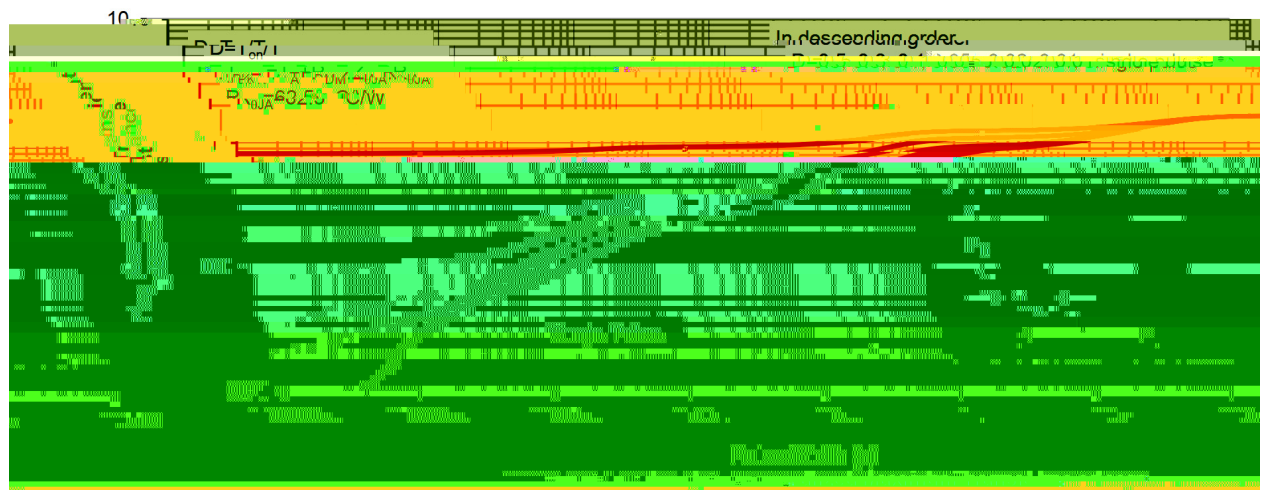
Parameter		Symbol	Rating	Unit
Drain–Source Voltage		V_{DSS}	-60	V
Gate–Body Leakage Voltage		V_{GSS}	± 20	V
Drain Current – Continuous		I_D	-3.5	A
Pulsed Drain Current		I_{DM}	-16	A
Power Dissipation		P_D	2	W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 150	
Maximum Junction-to-Ambient	Steady-State	$R_{\theta JA}$	62.5	/W

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-60	-4f1(	-606500.3(-4f14742.5(	

静态特性



三极管



4. 1. 2

